

MOSFET – Power, P-Channel, Single ATPAK

-60 V, -35 A, 29.5 m Ω

ATP113

Features

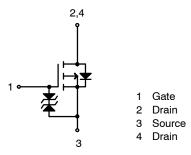
- ON-Resistance $R_{DS(on)}1 = 22.5 \text{ m}\Omega \text{ (typ)}$
- 4 V Drive
- Protection Diode in
- Input Capacitance Ciss = 2400 pF (typ)
- This Device is a Pb-Free and Halogen Free

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C) (Note 1)

Parameter	Symbol	Conditions	Value	Unit
Drain-to-Source Voltage	V_{DSS}		-60	٧
Gate-to-Source Voltage	V_{GSS}		±20	V
Drain Current (DC)	I _D		-35	Α
Drain Current (PW ≤ 10 µs)	I _{DP}	PW ≤ 10 μs, duty cycle ≤ 1%	-105	Α
Allowable Power Dissipation	P_{D}	Tc = 25°C	50	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) (Note 1)	E _{AS}		95	mJ
Avalanche Current (Note 2)	I _{AV}		-18	Α

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. $V_{DD} = -10 \text{ V}$, $L = 500 \mu\text{H}$, $I_{AV} = -18 \text{ A}$
- 2. $L \le 500 \mu H$, Single pulse



ELECTRICAL CONNECTION



DPAK (Single Gauge) / ATPAK CASE 369AM

MARKING DIAGRAM



ATP113 = Specific Device Code
Y = Year of Production
M = Assembly Operation Mo

M = Assembly Operation Month
W = Work Week in the Month

ORDERING INFORMATION

Device	Package	Shipping [†]
ATP113-TL-H	DPAK / ATPAK (Pb-Free and Halide Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

			Value			
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	$I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$	-60	_	-	V
Zero-Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -60 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	-1	μΑ
Gate to Source Leakage Current	I _{GSS}	V _{GS} = +16 V, V _{DS} = 0 V	-	-	+10	μΑ
Cutoff Voltage	V _{GS} (off)	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$	-1.2	_	-2.6	V
Forward Transfer Admittance	yfs	$V_{DS} = -10 \text{ V}, I_D = -18 \text{ A}$	-	37	-	S
Static Drain to Source On-State Resistance	R _{DS} (on)1	I _D = -18 A, V _{GS} = -10 V	-	22.5	29.5	mΩ
	R _{DS} (on)2	$I_D = -9 \text{ A}, V_{GS} = -4.5 \text{ V}$	-	27	38	mΩ
	R _{DS} (on)3	$I_D = -5 \text{ A}, V_{GS} = -4 \text{ V}$	-	29	44	mΩ
Input Capacitance	Ciss	V _{DS} = -20 V, f = 1 MHz	_	2400	-	pF
Output Capacitance	Coss		_	250	-	pF
Reverse Transfer Capacitance	Crss		-	195	-	pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.	_	15	-	ns
Rise Time	t _r		_	125	-	ns
Turn-OFF Delay Time	t _d (off)		_	250	-	ns
Fall Time	t _f		_	200	-	ns
Total Gate Charge	Qg	$V_{DS} = -30 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -35 \text{ A}$	-	55	-	nC
Gate to Source Charge	Qgs	1	-	7.5	-	nC
Gate to Drain "Miller" Charge	Qgd	1	-	12	-	nC
Diode Forward Voltage	V_{SD}	I _S = -35 A, V _{GS} = 0 V	-	-0.98	-1.5	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit

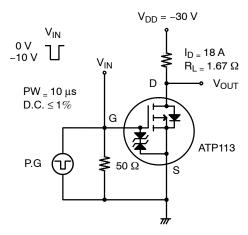
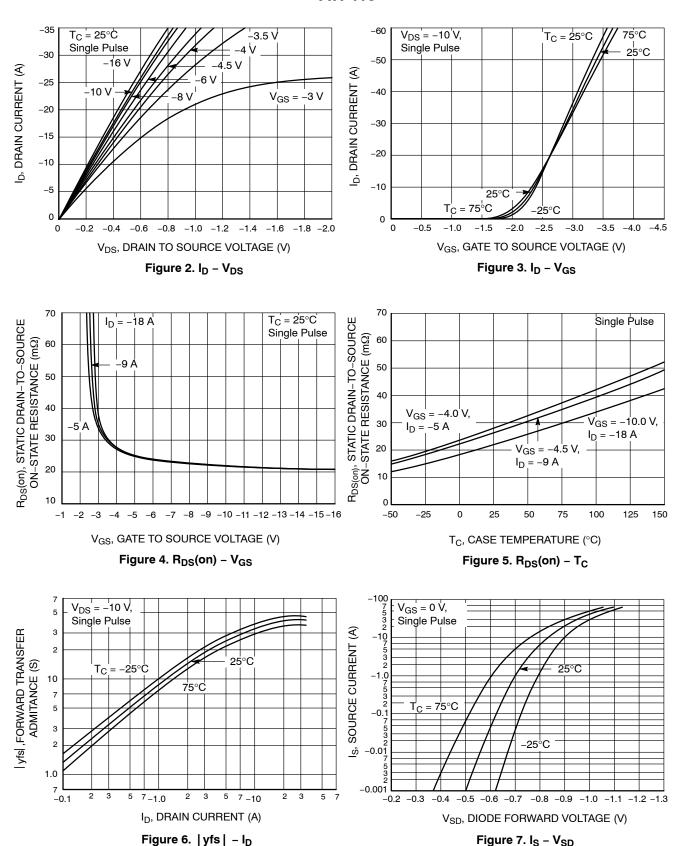
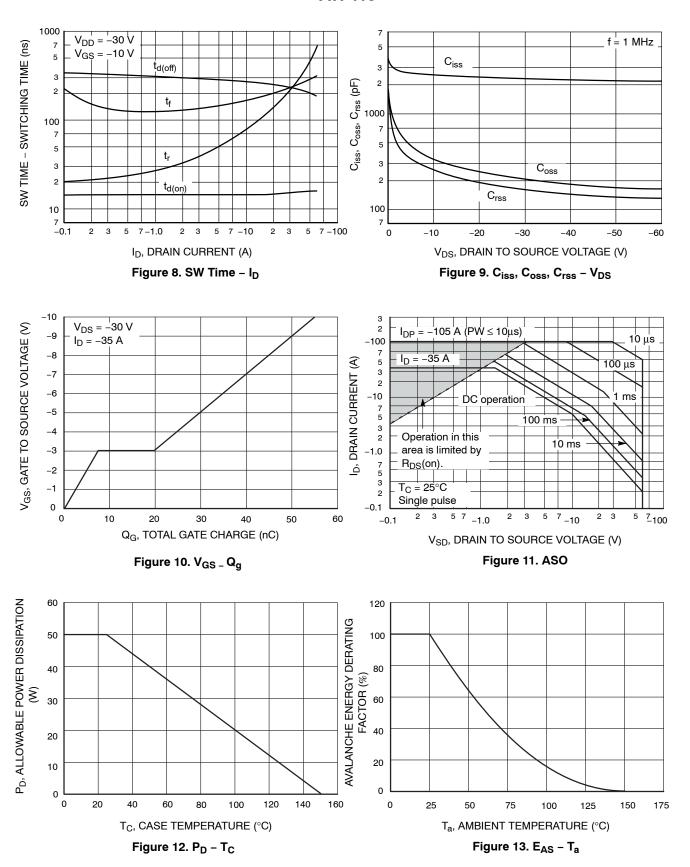


Figure 1. Switching Time Test Circuit





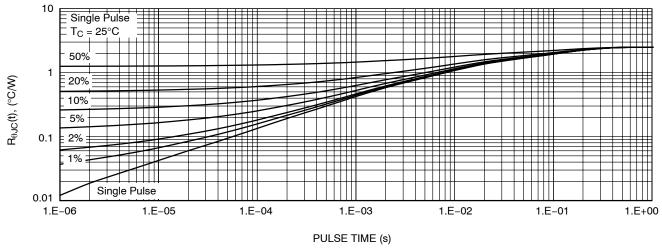
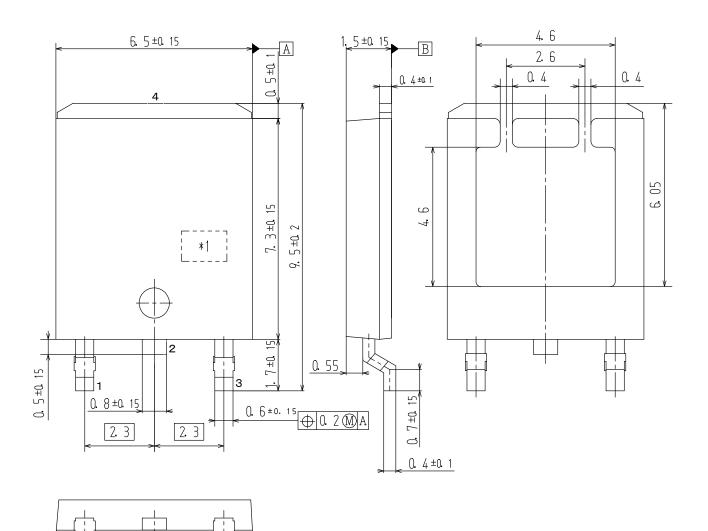


Figure 14. Thermal Response

DPAK (Single Gauge) / ATPAK CASE 369AM ISSUE O

DATE 29 FEB 2012





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